Diode Semiconductor Device - Page 1 of 1



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Inclosure Material:

Glass

Overall Length:

0.300 inches

Terminal Length:

Between 1.000 inches and 1.500 inches

Overall Diameter:

0.107 inches

End Application:

Aircraft, awacs, e-3a

Mounting Facility Quantity:

2

Mounting Method:

Terminal

Semiconductor Material:

Silicon

Voltage Rating In Volts Per Characteristic:

11.7 regulator voltage

Voltage Tolerance In Percent:

-5.0/+5.0

Current Rating Per Characteristic:

39.00 milliamperes repetitive peak forward current and 15.00 microamperes forward current, average peak

Power Rating Per Characteristic:

500.0 milliwatts small-signal input power, common-collector preset

Maximum Operating Tempurature Per Measurement Point:

175.0 degrees celsius junction

Special Features:

Voltage-reference type

Test Data Document:

81349-mil-prf-19500/157 specification (includes engineering type bulletins, brochures, etc., that reflect specification type data in specification format; excludes commercial catalogs, industry directories, and similar trade publications, reflecting general type data on certain environmental and performance requirements and test conditions that are shown as "typical", "average", "", etc.).

Terminal Type And Quantity:

2 uninsulated wire lead

Shelf Life:

N/a

Unit Of Measure:

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Demilitarization:

No

Fiig:

A110a0

Mil-std (military Standard):

Mil-prf-19500 spec.